TF-XTX-CV-A10

DATE: 21-Jun-12

P/N	DESCRIPTION	MAKER	PART NO.	UL NO./ Flame Class
1211100114	(TF)INDUCTOR.10uH.10%.SMD.0805.DCR=0.85 Ω.IDC=360mA.GOTREND.GNLC2012PR-100K	GOTREND	GNLC2012PR-100K	E218438/E75077/E84081/E174837,
121110106M	(TF)COIL.1.0uH.SMD.20%.4.7x4.0x2.0mm.DCR=21mohm.Idc=5A.ZenithTek.ZPWM-4020MP-1R0	ZenithTek	ZPWM-4020MP-1R0	E84081,
121110106S	(TF)COIL.1uH.20%.SMD.7.0*6.6*3.0mm.DCR=6.9mohm.Irms=11.8Amp.Panasonic.ETQP3W1R0WFN	Panasonic	ETQP3W1R0WFN	E215594,
121110156M	(TF)COIL.1.5uH.DCR=9.8mohm.Irms=9.6Amp.20%.7.0*6.6*3.0mm.SMD.Panasonic.ETQP3W1R5WFN	Panasonic	ETQP3W1R5WFN	E215594,
121110226T	(TF)COIL.2.2uH.30%.SMD.2.5*2.0*1.2mm.DCR=165mohm.Idc=1.78A.ZenithTek.ZAD-2512MES-2R2	ZenithTek	ZAD-2512MES-2R2	E258243,
1211133074	(TF)COIL.3.3uH.20%.SMD.7.0*6.6*3.0mm.DCR=25mohm.Irms=7Amp.Panasonic.ETQP3W3R3WFN	Panasonic	ETQP3W3R3WFN	E215594
1600000403	(TF)Switch.SMD 2S SPST.CTS.218-2LPST-P	CTS	218-2LPST-P	E10412
16515A2991	(TF)DDR3 SODIMM SKT.SMD.H=6.0mm.204P.REVERSE.1.5V.FOXCONN.AS0A626-JER6-7H	FOXCONN	AS0A626-JER6-7H	E54705,
1653150221	(TF)PCB SKT.50*2P.180D.(F).SMD.HIROSE.FX8-100P-SV(92)	HIROSE	FX8-100P-SV(92)	E109088,
1655902122	(TF)WAFER BOX.2Pin.90D.(M).Pitch=1.25mm.SMD.CATCH.1201-700-02RM	CATCH	1201-700-02RM	E119177(M),
1655907130	(TF)Wafer Box.7P.90D(M).SMD.1.0mm.CATCH.1204-700-07RM	CATCH	1204-700-07RM	E52579,
1655912130	(TF)WAFER BOX.12P.90D(M).1.0mm.SMD.CATCH.1204-700-12RM	CATCH	1204-700-12RM	E52579,
175011901C	(TF)BATTERY.3V.MAXELL.CR2032M1S8-LF	MAXELL	CR2032M1S8-LF	MH12568(N),E255532,

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1907XCV002	(TF)PCB.XTX-CV.Rev.A1.0_0_0.8Layers Blue.1*1.Thickness=1.8mm.114mmx95mmx1.8mm	L-BRIDGE		E120558
1998666626	(TF)Thermal Pad.15*15*1.0mm.PFM-532I.INVIN	INVIN	PAD 15*15*1T	E153203,